Application Number: 09/559,757

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**AMENDMENTS TO THE SPECIFICATION:** 

1. Please amend the paragraph beginning on page 18, line 27, and ending on page 19,

line 2, as follows:

FIG. 17 is a microscopic photograph of a semiconductor structure containing a silicon

nitride film oxidized by the conventional oxidizing method according to the present invention;

and

2. Please amend the paragraph beginning on page 19, line 3, and ending on page 19, line

6, as follows:

FIG. 18 is a microscopic photograph of a semiconductor structure containing a silicon

nitride film oxidized by the <u>conventional</u> oxidizing method according to the present invention.

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